

## G5: NEGF simulation of graphene-based devices

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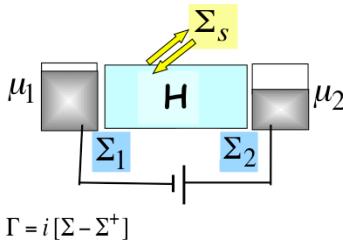
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## G5.1. NEGF equations with elastic scatterers in equilibrium



$$\Gamma = i[\Sigma - \Sigma^+]$$

$$\varepsilon \rightarrow [H]$$

$$\gamma \rightarrow [\Gamma], [\Sigma]$$

$$n(E) \rightarrow [G^n(E)]$$

$$D(E) \rightarrow [A(E)]$$

**Green function**  $[G] = [EI - H - \Sigma_1 - \Sigma_2 - \Sigma_s]^{-1}$

**"Density of states"**  $A = i[G - G^+]$

**"Electron density"**

$$G^n = G\Gamma_2 G^+ f_2 + G\Gamma_1 G^+ f_1 + G\Sigma_s^{in} G^+$$

**Current**  $\frac{I_1}{q/\hbar} = \text{Trace} ([\Gamma_1 A] f_1 - [\Gamma_1 G^n])$

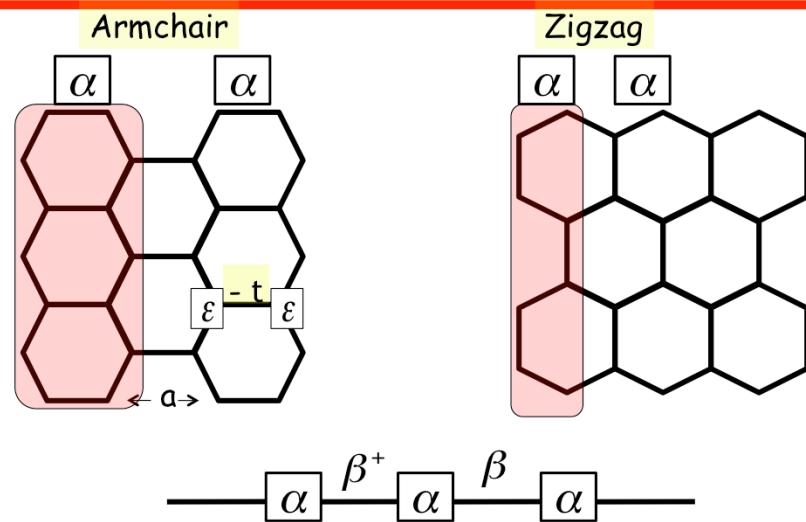
**Dephasing**  $[\Sigma_s^{in}] = D[G^n]$

$$[\Sigma_s] = D[G]$$



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## G5.2. Tight-binding model



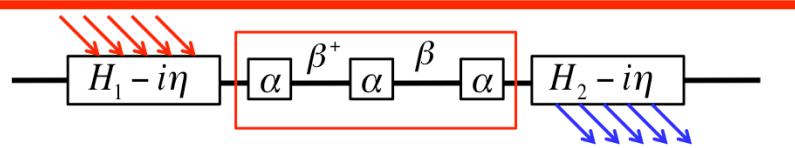
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### G5.3. Contact self-energy



$$\begin{bmatrix} E + i\eta - H_1 & -\beta & 0 \\ -\beta^+ & E - H & -\beta \\ 0 & -\beta^+ & E + i\eta - H_2 \end{bmatrix} \begin{Bmatrix} \Phi_1 + \chi_1 \\ \psi \\ \chi_2 \end{Bmatrix} = \begin{Bmatrix} s_1 \\ 0 \\ 0 \end{Bmatrix} \quad \Sigma_2 = \beta g_2 \beta^+$$

$$[E - H - \Sigma_1 - \Sigma_2] \{\psi\} = \{S_1\} \quad \text{Iterative solution of}$$

$\{S_1\} \xrightarrow{[\Sigma_1]} [H] \xrightarrow{[\Sigma_2]} \text{yields } g_2$